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Two layers of CVD graphene film on SiO₂/Si wafer

Properties of Graphene Film:

Two layers of single layer CVD graphene films are transferred onto 285 nm p-doped SiO_2/Si wafer

Size: 1cmx1cm; 4 pack

Each graphene film is transferred consecutively onto the wafer

The thickness and quality of our graphene film is controlled by Raman Spectroscopy

The graphene coverage of this product is about 98%

The graphene film is continuous, with minor holes and organic residues

Each graphene film is predominantly single layer (more than 95%) with occasional small multilayer islands (less than 5% bi-layers)

Each graphene film is polycrystalline, i.e. it consists of grains with different crystallographic orientation

There is no A-B stacking order. The graphene films are randomly oriented with respect to each other

Sheet Resistance: 215-700 Ω/square

Properties of Silicon/Silicon Dioxide Wafers:

- Oxide Thickness: 285 nm
- Color: Violet
- Wafer thickness: 525 micron
- Resistivity: 0.001-0.005 ohm-cm
- Type/Dopant: P/Boron
- Orientation: <100>
- Front Surface: Polished
- Back Surface: Etched



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Applications:

Graphene electronics and transistors Conductive coatings Aerospace industry applications Support for metallic catalysts Microactuators MEMS and NEMS Chemical and biosensors Multifunctional materials based on graphene Graphene Research